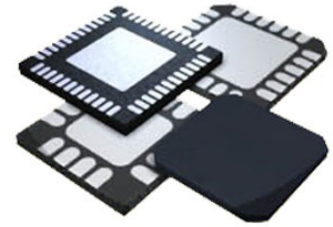


Small Signal Field-Effect Transistor, 6.6A I(D), 20V, 1Element, P-Channel, Silicon, Metal-oxide Semiconductor FET, 2 X 2MM, 0.8MM HEIGHT, ANTIMONY AND HALOGEN FREE, ROHS COMPLIANT, MO-229, MICROFET-6

Manufacturers	<a href="#">ON Semiconductor, LLC</a>
Package/Case	QFN-6
Product Type	Transistors
RoHS	Green
Lifecycle	



Images are for reference only

Please submit RFQ for FDMA291P or [Email to us: sales@ovaga.com](mailto:sales@ovaga.com) We will contact you in 12 hours.

[RFQ](#)

## General Description

This device is designed specifically for battery charge or load switching in cellular handset and other ultraportable applications. It features a MOSFET with low on-state resistance. The MicroFET 2x2 package offers exceptional thermal performance for its physical size and is well suited to linear mode applications.

## Application

ONSEMI

## Related Products



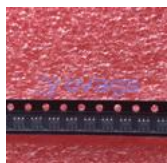
### [FDC645N](#)

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SSOT-6



### [FDC637BNZ](#)

ON Semiconductor, LLC  
SSOT-6



### [FDC6305N](#)

ON Semiconductor, LLC  
SSOT-6



### [FDC602P](#)

ON Semiconductor, LLC  
SOT163



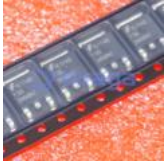
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